

QUADRUPLE DIFFERENTIAL LINE DRIVER

Check for Samples: [AM26C31](#)

FEATURES

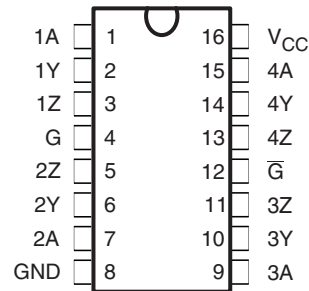
- Meets or Exceeds the Requirements of TIA/EIA-422-B and ITU Recommendation V.11
- Low Power, $I_{CC} = 100 \mu A$ Typ
- Operates From a Single 5-V Supply
- High Speed, $t_{PLH} = t_{PHL} = 7 \text{ ns}$ Typ
- Low Pulse Distortion, $t_{sk(p)} = 0.5 \text{ ns}$ Typ
- High Output Impedance in Power-Off Conditions
- Improved Replacement for AM26LS31
- Available in Q-Temp Automotive
 - High-Reliability Automotive Applications
 - Configuration Control/Print Support
 - Qualification to Automotive Standards

DESCRIPTION/ORDERING INFORMATION

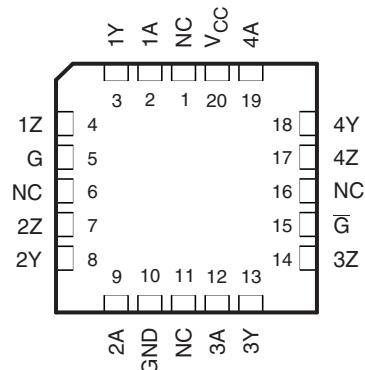
The AM26C31 is a differential line driver with complementary outputs, designed to meet the requirements of TIA/EIA-422-B and ITU (formerly CCITT). The 3-state outputs have high-current capability for driving balanced lines, such as twisted-pair or parallel-wire transmission lines, and they provide the high-impedance state in the power-off condition. The enable functions are common to all four drivers and offer the choice of an active-high (G) or active-low ($\bar{G}$) enable input. BiCMOS circuitry reduces power consumption without sacrificing speed.

The AM26C31C is characterized for operation from 0°C to 70°C, the AM26C31I is characterized for operation from –40°C to 85°C, the AM26C31Q is characterized for operation over the automotive temperature range of –40°C to 125°C, and the AM26C31M is characterized for operation over the full military temperature range of –55°C to 125°C.

AM26C31M. . . J OR W PACKAGE
AM26C31Q. . . D PACKAGE
AM26C31C. . . D, DB, OR NS PACKAGE
AM26C31I. . . D, DB, N, NS, OR PW PACKAGE
(TOP VIEW)



AM26C31M. . . FK PACKAGE
(TOP VIEW)



NC – No internal connection



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

ORDERING INFORMATION

T_A	PACKAGE⁽¹⁾ ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	PDIP (N)	Tube of 25	AM26C31CN	AM26C31CN
	SOIC (D)	Tube of 40	AM26C31CD	AM26C31C
		Reel of 2500	AM26C31CDR	
	SOP (NS)	Reel of 2000	AM26C31CNSR	26C31
	SSOP (DB)	Reel of 2000	AM26C31CDBR	26C31
–40°C to 85°C	PDIP (N)	Tube of 25	AM26C31IN	AM26C31IN
	SOIC (D)	Tube of 40	AM26C31ID	AM26C31I
		Reel of 2500	AM26C31IDR	
	SOP (NS)	Reel of 2000	AM26C31INSR	26C31I
	SSOP (DB)	Reel of 2000	AM26C31IDBR	26C31I
–40°C to 125°C	SOIC (D)	Tube of 40	AM26C31QD	AM26C31QD
		Reel of 2500	AM26C31QDR	
	CDIP (J)	Tube of 25	AM26C31MJ	AM26C31MJ
–55°C to 125°C	CFP (W)	Tube of 150	AM26C31MW	AM26C31MW
	LCCC (FK)	Tube of 55	AM26C31MFK	AM26C31MFK

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

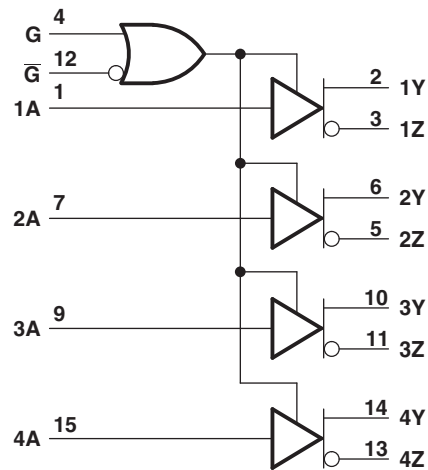
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

**Table 1. FUNCTION TABLE
(Each Driver)⁽¹⁾**

INPUT A	ENABLES		OUTPUTS	
	G	$\overline{G}$	Y	Z
H	H	X	H	L
L	H	X	L	H
H	X	L	H	L
L	X	L	L	H
X	L	H	Z	Z

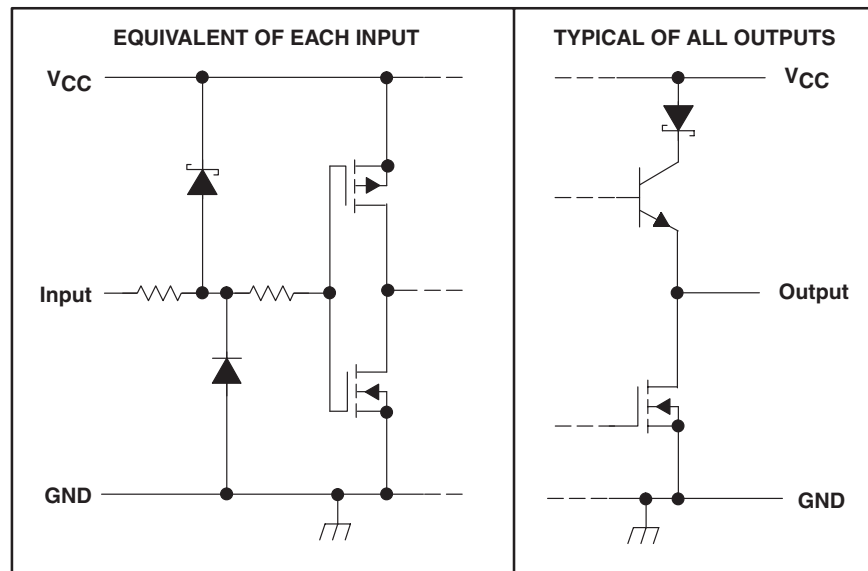
(1) H = High level, L = Low level, X = Irrelevant,
Z = High impedance (off)

LOGIC DIAGRAM (POSITIVE LOGIC)



Pin numbers shown are for the D, DB, J, N, NS, PW, and W packages.

SCHEMATICS OF INPUTS AND OUTPUTS



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{CC}	Supply voltage range ⁽²⁾	–0.5	7	V
V _I	Input voltage range	–0.5	V _{CC} + 0.5	V
V _{ID}	Differential input voltage range	–14	14	V
V _O	Output voltage range	–0.5	7	
I _{IK} I _{OK}	Input or output clamp current		±20	mA
I _O	Output current		±150	mA
	V _{CC} current		200	mA
	GND current	–200		mA
θ _{JA}	Package thermal impedance ^{(3) (4)}	D package	73	°C/W
		DB package	82	
		N package	67	
		NS package	64	
		PW package	108	
T _J	Operating virtual junction temperature		150	°C
T _{stg}	Storage temperature range	–65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to the network ground terminal.
- (3) Maximum power dissipation is a function of T_{J(max)}, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_{J(max)} – T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	4.5	5	5.5	V
V _{ID}	Differential input voltage		±7		V
V _{IH}	High-level input voltage	2			V
V _{IL}	Low-level input voltage			0.8	V
I _{OH}	High-level output current			–20	mA
I _{OL}	Low-level output current			20	mA
T _A	Operating free-air temperature	AM26C31C	0	70	°C
		AM26C31I	–40	85	
		AM26C31Q	–40	125	
		AM26C31M	–55	125	

ELECTRICAL CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	AM26C31C AM26C31I			UNIT
			MIN	TYP ⁽¹⁾	MAX	
V _{OH}	High-level output voltage	I _O = –20 mA	2.4	3.4		V
V _{OL}	Low-level output voltage	I _O = 20 mA		0.2	0.4	V
V _{OD}	Differential output voltage magnitude	R _L = 100 Ω, See Figure 1	2	3.1		V
Δ V _{OD}	Change in magnitude of differential output voltage ⁽²⁾	R _L = 100 Ω, See Figure 1			±0.4	V
V _{OC}	Common-mode output voltage	R _L = 100 Ω, See Figure 1			3	V
Δ V _{OC}	Change in magnitude of common-mode output voltage ⁽²⁾	R _L = 100 Ω, See Figure 1			±0.4	V
I _I	Input current	V _I = V _{CC} or GND			±1	μA
I _{O(off)}	Driver output current with power off	V _{CC} = 0 V _O = 6 V V _O = –0.25 V			100 –100	μA
I _{OS}	Driver output short-circuit current	V _O = 0	–30		–150	mA
I _{OZ}	High-impedance off-state output current	V _O = 2.5 V V _O = 0.5 V			20 –20	μA
I _{CC}	Quiescent supply current	I _O = 0 V _I = 0 or 5 V V _I = 2.4 V or 0.5 V ⁽³⁾			100 1.5 3	μA mA
C _i	Input capacitance			6		pF

(1) All typical values are at V_{CC} = 5 V and T_A = 25°C.

(2) Δ|V_{OD}| and Δ|V_{OC}| are the changes in magnitude of V_{OD} and V_{OC}, respectively, that occur when the input is changed from a high level to a low level.

(3) This parameter is measured per input. All other inputs are at 0 or 5 V.

SWITCHING CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	AM26C31C AM26C31I			UNIT
			MIN	TYP ⁽¹⁾	MAX	
t _{PLH}	Propagation delay time, low-to-high-level output	S1 is open, See Figure 2	3	7	12	ns
t _{PHL}	Propagation delay time, high-to-low-level output		3	7	12	
t _{sk(p)}	Pulse skew time (t _{PLH} – t _{PHL})	S1 is open, See Figure 2		0.5	4	ns
t _{r(OD)} , t _{f(OD)}	Differential output rise and fall times	S1 is open, See Figure 3		5	10	ns
t _{PZH}	Output enable time to high level	S1 is closed, See Figure 4		10	19	ns
t _{PZL}	Output enable time to low level			10	19	
t _{PHZ}	Output disable time from high level	S1 is closed, See Figure 4		7	16	ns
t _{PLZ}	Output disable time from low level			7	16	
C _{pd}	Power dissipation capacitance (each driver) ⁽²⁾	S1 is open, See Figure 2		170		pF

(1) All typical values are at V_{CC} = 5 V and T_A = 25°C.

(2) C_{pd} is used to estimate the switching losses according to P_D = C_{pd} × V_{CC}² × f, where f is the switching frequency.

ELECTRICAL CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	AM26C31Q AM26C31M			UNIT
			MIN	TYP ⁽¹⁾	MAX	
V _{OH}	High-level output voltage	I _O = –20 mA	2.2	3.4		V
V _{OL}	Low-level output voltage	I _O = 20 mA		0.2	0.4	V
V _{OD}	Differential output voltage magnitude	R _L = 100 Ω, See Figure 1	2	3.1		V
Δ V _{OD}	Change in magnitude of differential output voltage ⁽²⁾	R _L = 100 Ω, See Figure 1			±0.4	V
V _{OC}	Common-mode output voltage	R _L = 100 Ω, See Figure 1			3	V
Δ V _{OC}	Change in magnitude of common-mode output voltage ⁽²⁾	R _L = 100 Ω, See Figure 1			±0.4	V
I _I	Input current	V _I = V _{CC} or GND			±1	μA
I _{O(off)}	Driver output current with power off	V _{CC} = 0 V _O = 6 V V _O = –0.25 V			100 –100	μA
I _{OS}	Driver output short-circuit current	V _O = 0			–170	mA
I _{OZ}	High-impedance off-state output current	V _O = 2.5 V V _O = 0.5 V			20 –20	μA
I _{CC}	Quiescent supply current	I _O = 0 V _I = 0 or 5 V V _I = 2.4 V or 0.5 V ⁽³⁾			100 3.2	μA mA
C _i	Input capacitance			6		pF

(1) All typical values are at V_{CC} = 5 V and T_A = 25°C.

(2) Δ|V_{OD}| and Δ|V_{OC}| are the changes in magnitude of V_{OD} and V_{OC}, respectively, that occur when the input is changed from a high level to a low level.

(3) This parameter is measured per input. All other inputs are at 0 or 5 V.

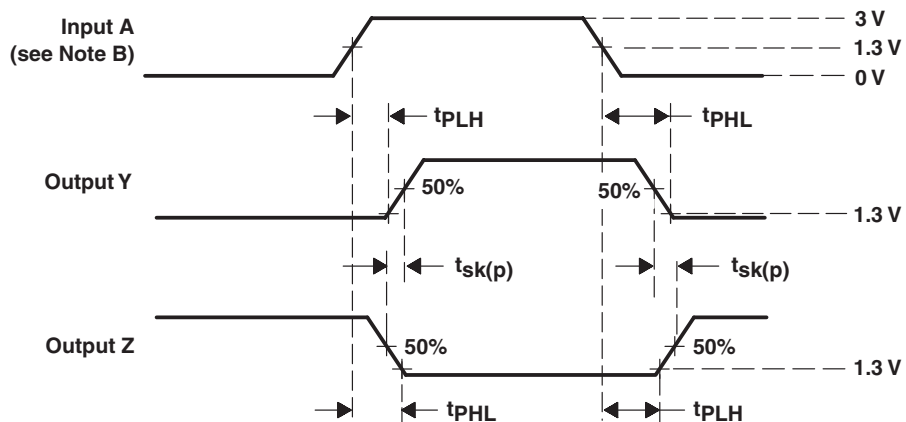
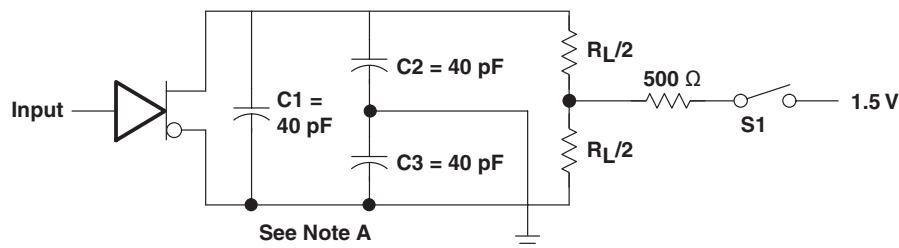
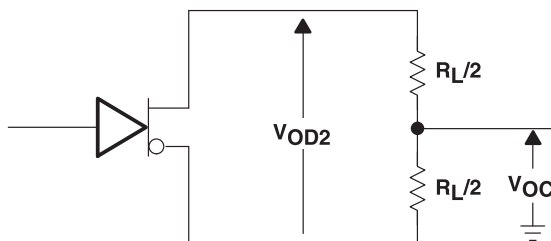
SWITCHING CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

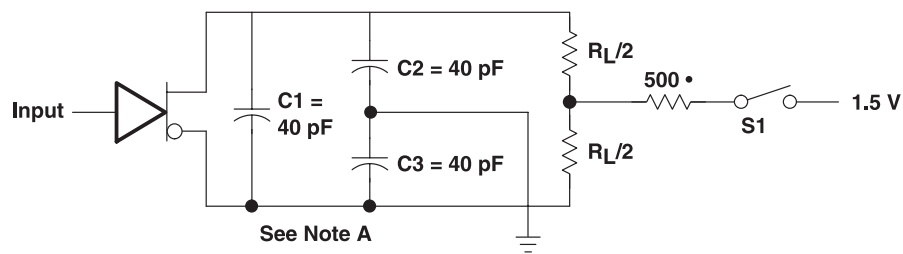
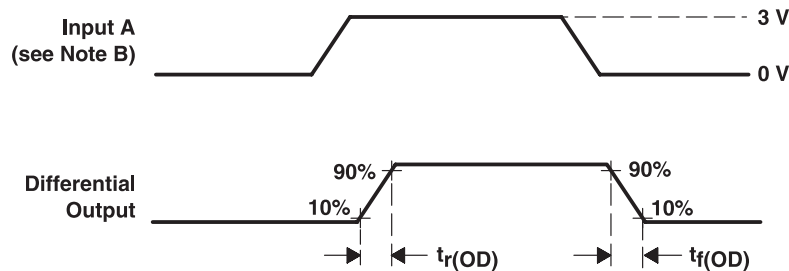
PARAMETER		TEST CONDITIONS	AM26C31Q AM26C31M			UNIT
			MIN	TYP ⁽¹⁾	MAX	
t _{PLH}	Propagation delay time, low-to-high-level output	S1 is open, See Figure 2		7	12	ns
t _{PHL}	Propagation delay time, high-to-low-level output			6.5	12	
t _{sk(p)}	Pulse skew time (t _{PLH} – t _{PHL})	S1 is open, See Figure 2		0.5	4	ns
t _{r(OD)} , t _{f(OD)}	Differential output rise and fall times	S1 is open, See Figure 3		5	12	ns
t _{PZH}	Output enable time to high level	S1 is closed, See Figure 4		10	19	ns
t _{PZL}	Output enable time to low level			10	19	
t _{PHZ}	Output disable time from high level	S1 is closed, See Figure 4		7	16	ns
t _{PLZ}	Output disable time from low level			7	16	
C _{pd}	Power dissipation capacitance (each driver) ⁽²⁾	S1 is open, See Figure 2		100		pF

(1) All typical values are at V_{CC} = 5 V and T_A = 25°C.

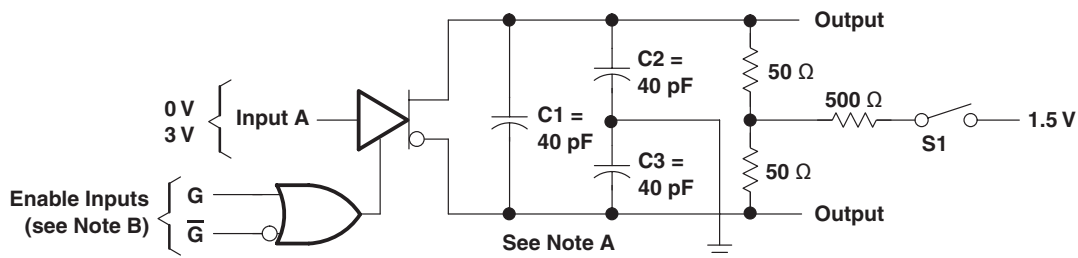
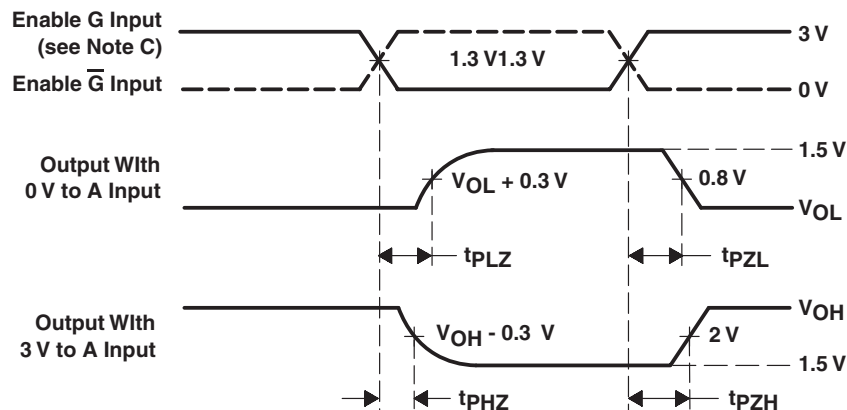
(2) C_{pd} is used to estimate the switching losses according to P_D = C_{pd} × V_{CC}² × f, where f is the switching frequency.



- A. C1, C2, and C3 include probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1$ MHz, duty cycle $\leq 50\%$, and $t_r, t_f \leq 6$ ns.

PARAMETER MEASUREMENT INFORMATION (continued)**TEST CIRCUIT****VOLTAGE WAVEFORMS****Figure 3. Differential-Output Rise- and Fall-Time Waveforms and Test Circuit**

- A. C1, C2, and C3 include probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR $\leq$ 1 MHz, duty cycle $\leq$ 50%, and $t_r, t_f \leq$ 6 ns.
- C. Each enable is tested separately.

**TEST CIRCUIT****VOLTAGE WAVEFORMS****Figure 4. Output Enable- and Disable-Time Waveforms and Test Circuit**

TYPICAL CHARACTERISTICS

SUPPLY CURRENT
vs
SWITCHING FREQUENCY

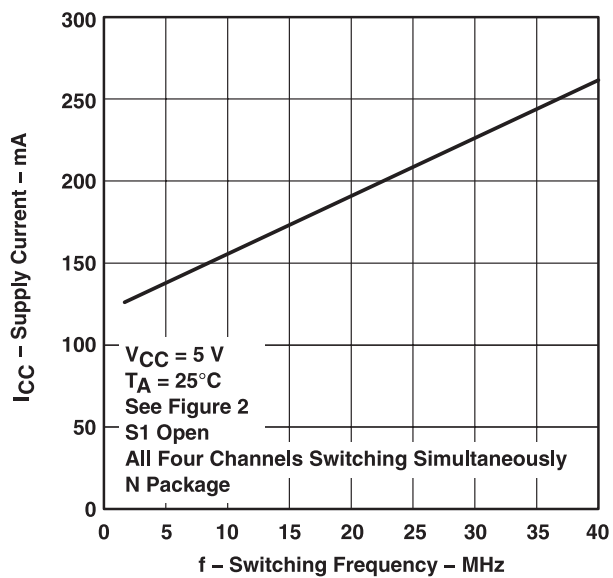


Figure 5.

REVISION HISTORY

Changes from Revision M (June 2008) to Revision N

Page

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- Changed units to mA from μ A to fix units typo. [4](#)
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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9163901M2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9163901M2A AM26C31M	Samples
5962-9163901MEA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901ME A AM26C31M	Samples
5962-9163901MFA	ACTIVE	CFP	W	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901MF A AM26C31M	Samples
5962-9163901Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9163901Q2A AM26C31 MFKB	Samples
5962-9163901QEA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901QE A AM26C31MJB	Samples
5962-9163901QFA	ACTIVE	CFP	W	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901QF A AM26C31MWB	Samples
AM26C31CD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Samples
AM26C31CDBLE	OBSOLETE	SSOP	DB	16		TBD	Call TI	Call TI	0 to 70		
AM26C31CDBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Samples
AM26C31CDBRE4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Samples
AM26C31CDBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Samples
AM26C31CDE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Samples
AM26C31CDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Samples
AM26C31CDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
AM26C31CDRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Samples
AM26C31CDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Samples
AM26C31CN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	AM26C31CN	Samples
AM26C31CNE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	AM26C31CN	Samples
AM26C31CNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Samples
AM26C31CNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Samples
AM26C31CNSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Samples
AM26C31ID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IDBLE	OBSOLETE	SSOP	DB	16		TBD	Call TI	Call TI	-40 to 85		
AM26C31IDBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IDBRE4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IDBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IDE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IDRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	AM26C31IN	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
AM26C31INE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	AM26C31IN	Samples
AM26C31INSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31INSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9163901Q2A AM26C31 MFKB	Samples
AM26C31MJB	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901QE A AM26C31MJB	Samples
AM26C31MWB	ACTIVE	CFP	W	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901QF A AM26C31MWB	Samples
AM26C31QD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AM26C31Q	Samples
AM26C31QDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	26C31Q	Samples
AM26C31QDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AM26C31Q	Samples
AM26C31QDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	26C31Q	Samples

⁽¹⁾ The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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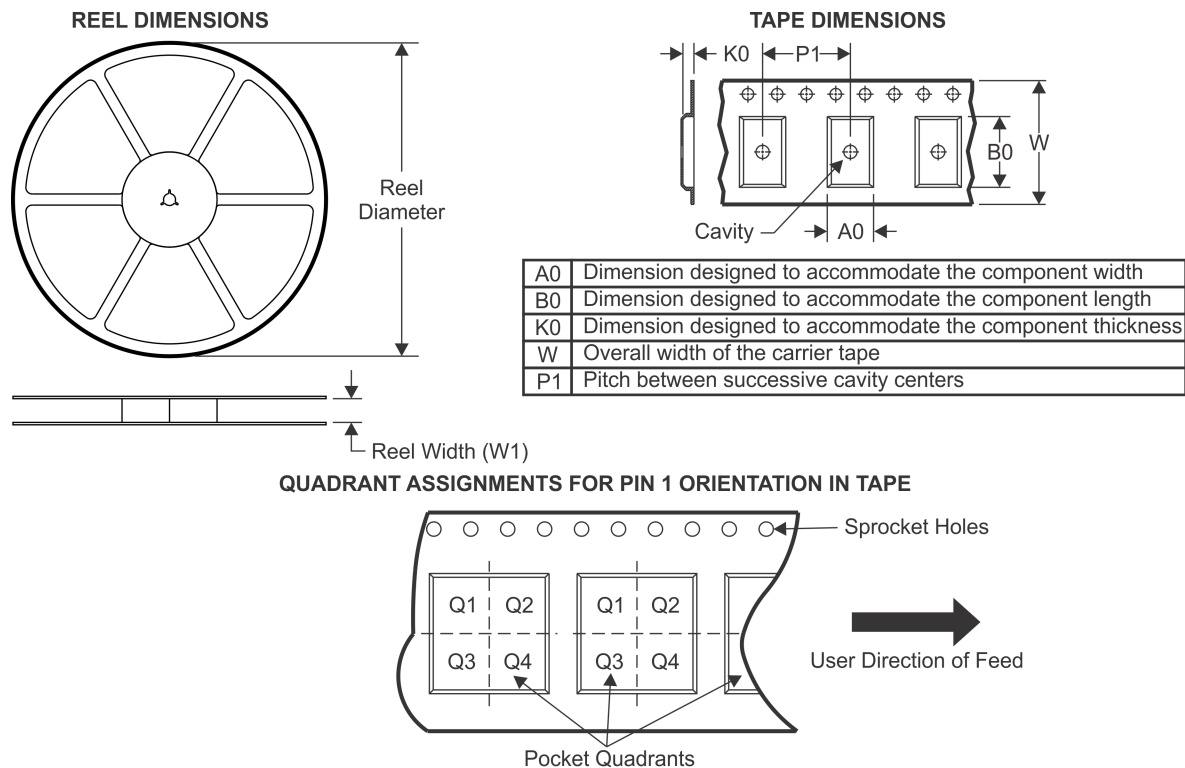
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF AM26C31, AM26C31M :

- Catalog: [AM26C31](#)
- Enhanced Product: [AM26C31-EP](#), [AM26C31-EP](#)
- Military: [AM26C31M](#)

NOTE: Qualified Version Definitions:

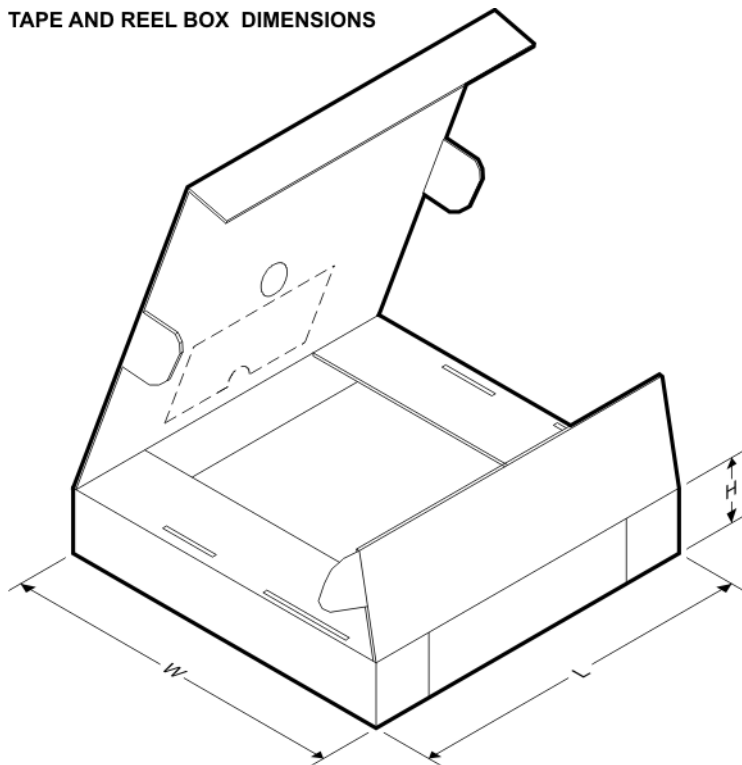
-
- Catalog - TI's standard catalog product
 - Enhanced Product - Supports Defense, Aerospace and Medical Applications
 - Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
AM26C31CDBR	SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
AM26C31CDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26C31IDBR	SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
AM26C31IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26C31IDR	SOIC	D	16	2500	330.0	16.8	6.5	10.3	2.1	8.0	16.0	Q1
AM26C31IDRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26C31IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
AM26C31QDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26C31QDRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



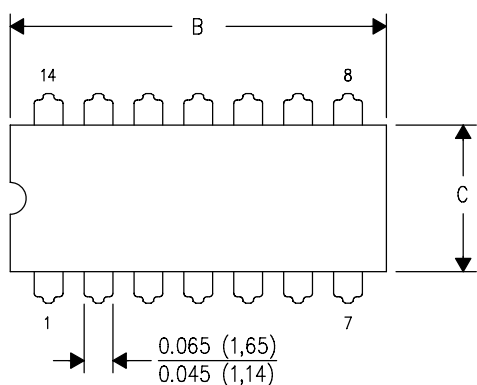
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
AM26C31CDBR	SSOP	DB	16	2000	367.0	367.0	38.0
AM26C31CDR	SOIC	D	16	2500	333.2	345.9	28.6
AM26C31IDBR	SSOP	DB	16	2000	367.0	367.0	38.0
AM26C31IDR	SOIC	D	16	2500	333.2	345.9	28.6
AM26C31IDR	SOIC	D	16	2500	364.0	364.0	27.0
AM26C31IDRG4	SOIC	D	16	2500	333.2	345.9	28.6
AM26C31IPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
AM26C31QDR	SOIC	D	16	2500	367.0	367.0	38.0
AM26C31QDRG4	SOIC	D	16	2500	333.2	345.9	28.6

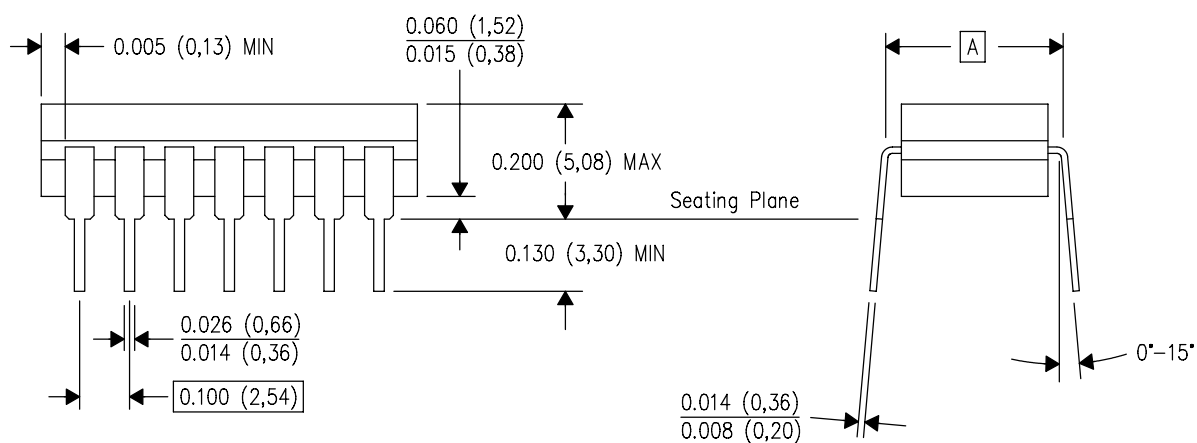
J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)

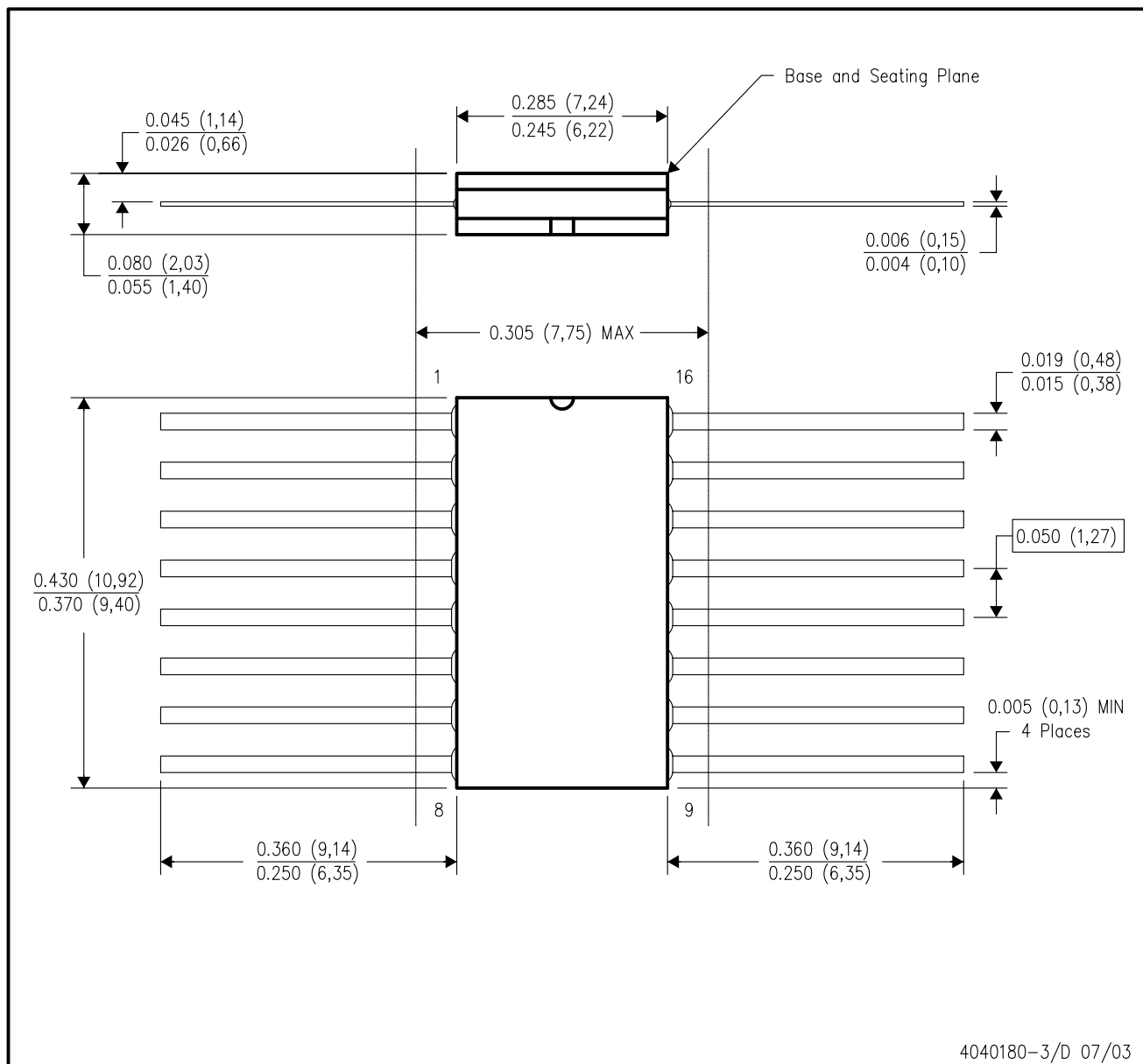


4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

W (R-GDFP-F16)

CERAMIC DUAL FLATPACK

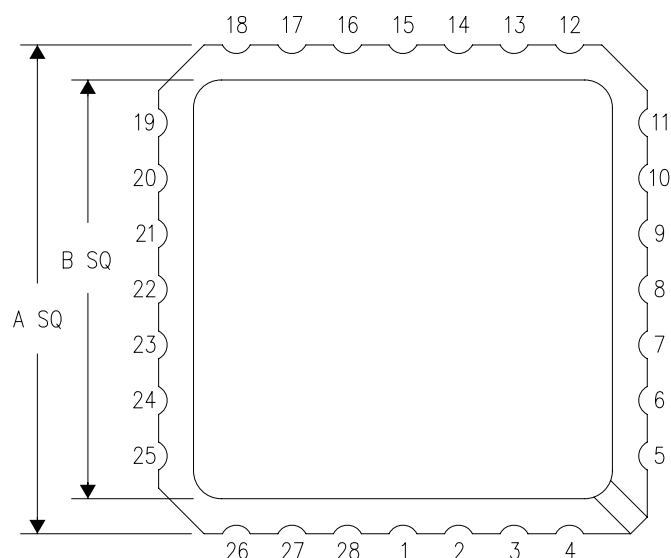


- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only.
 - E. Falls within MIL STD 1835 GDFP1-F16 and JEDEC MO-092AC

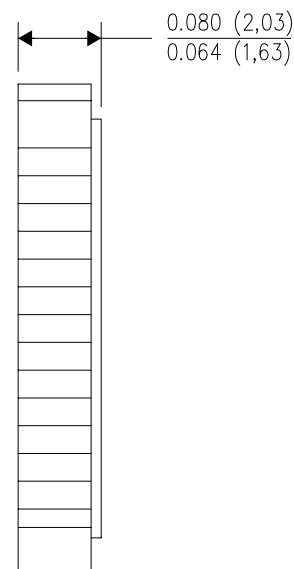
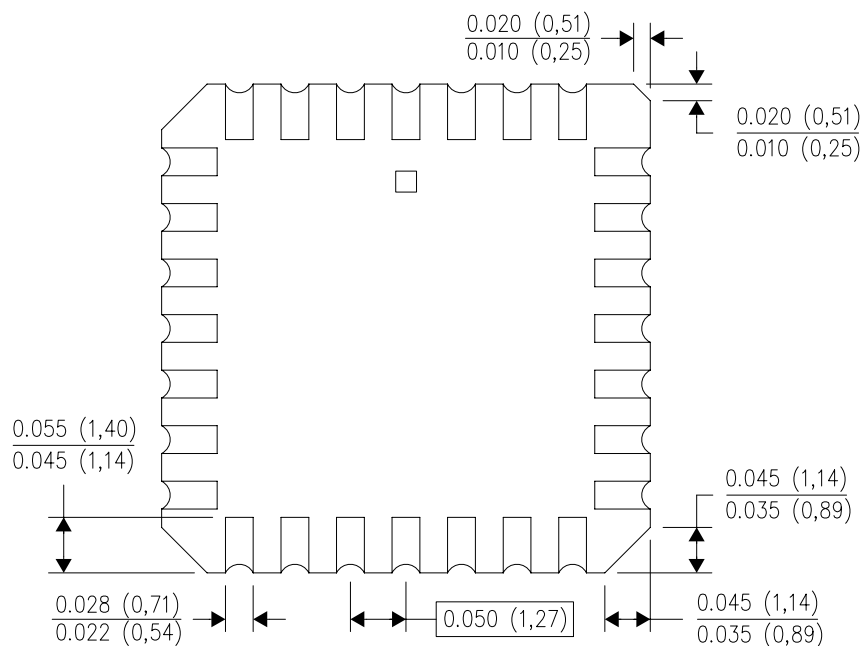
FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



NO. OF TERMINALS **	A		B	
	MIN	MAX	MIN	MAX
20	0.342 (8,69)	0.358 (9,09)	0.307 (7,80)	0.358 (9,09)
28	0.442 (11,23)	0.458 (11,63)	0.406 (10,31)	0.458 (11,63)
44	0.640 (16,26)	0.660 (16,76)	0.495 (12,58)	0.560 (14,22)
52	0.740 (18,78)	0.761 (19,32)	0.495 (12,58)	0.560 (14,22)
68	0.938 (23,83)	0.962 (24,43)	0.850 (21,6)	0.858 (21,8)
84	1.141 (28,99)	1.165 (29,59)	1.047 (26,6)	1.063 (27,0)

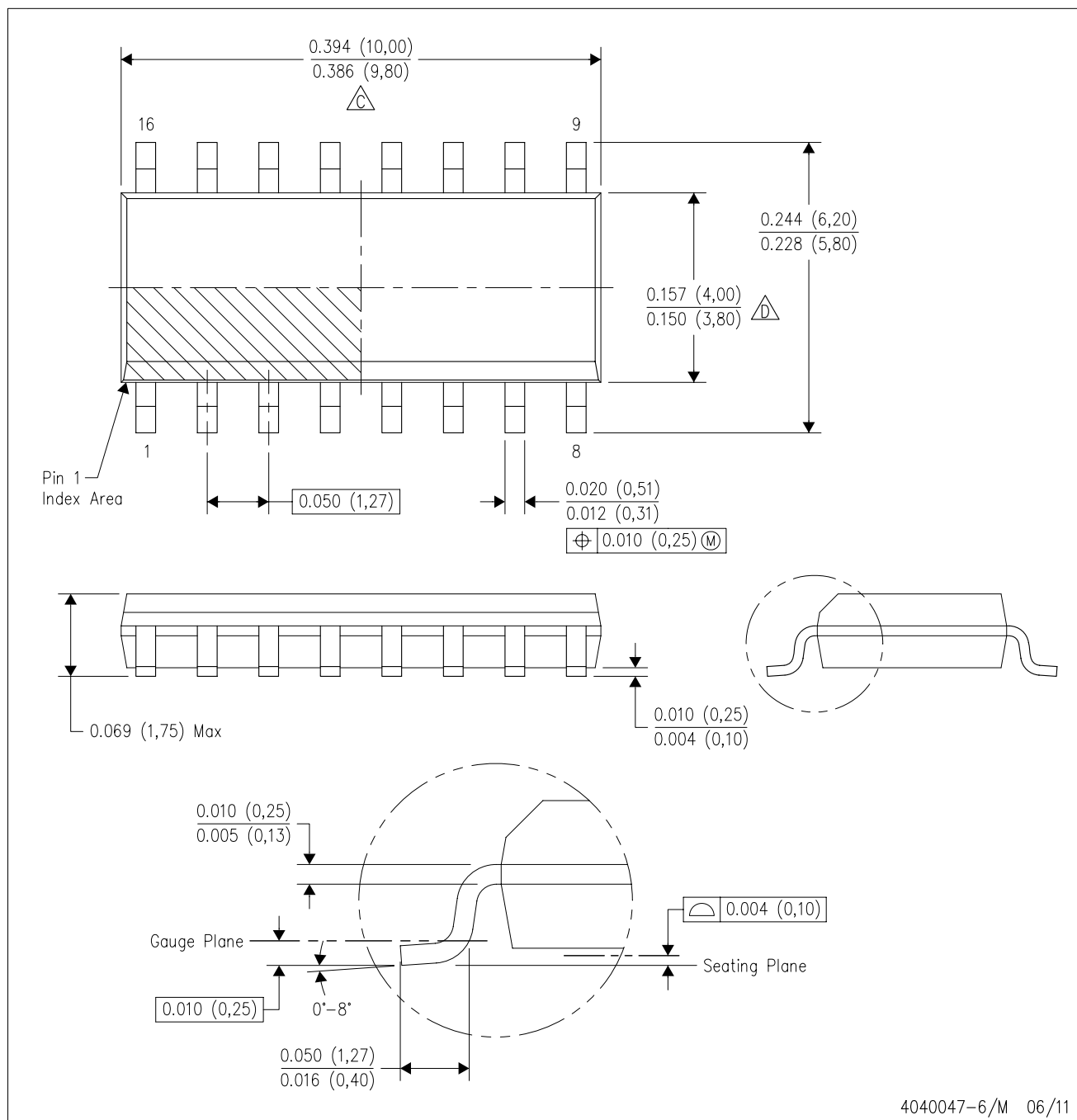


4040140/D 01/11

- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This package can be hermetically sealed with a metal lid.
 - Falls within JEDEC MS-004

D (R-PDSO-G16)

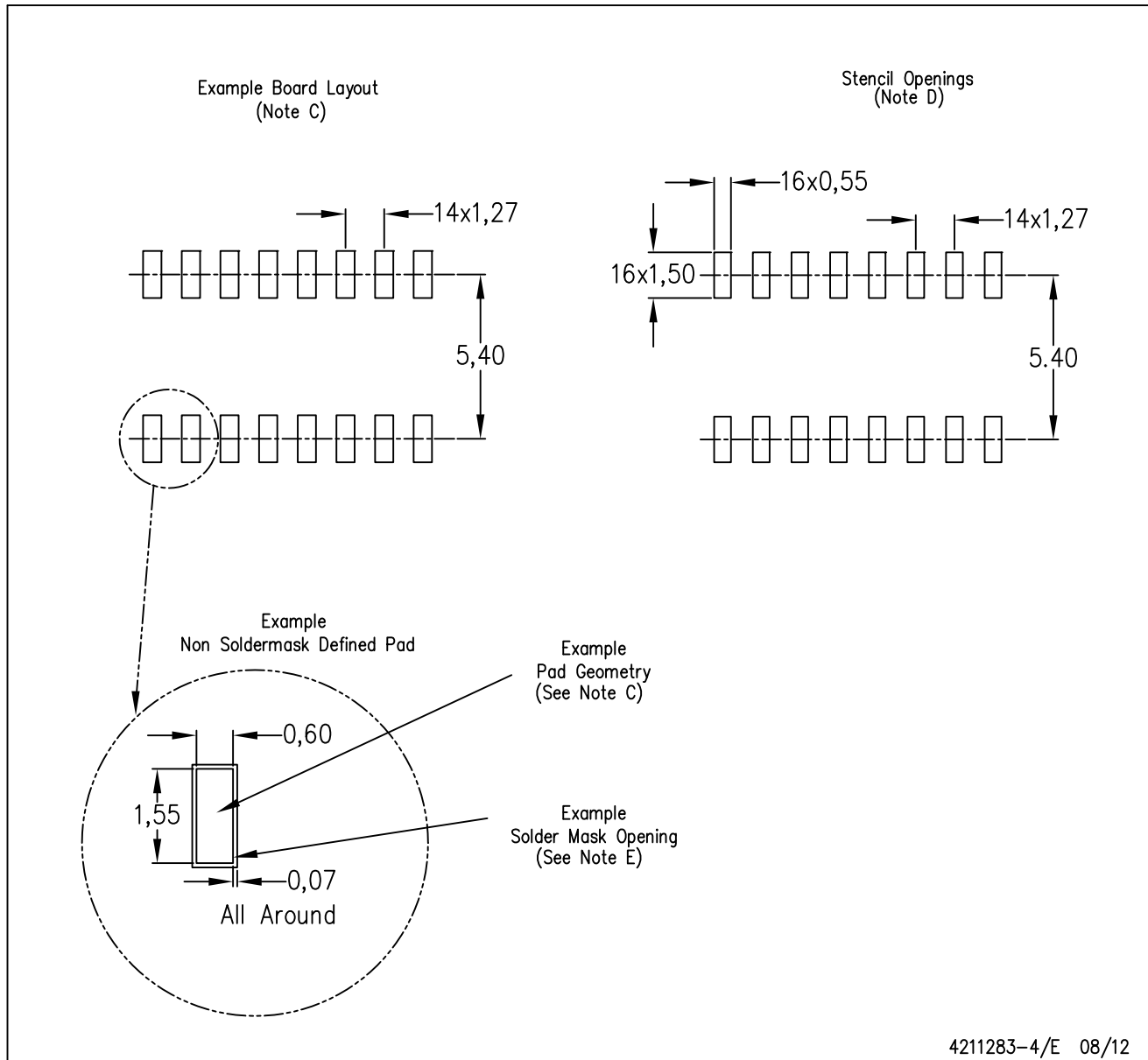
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16)

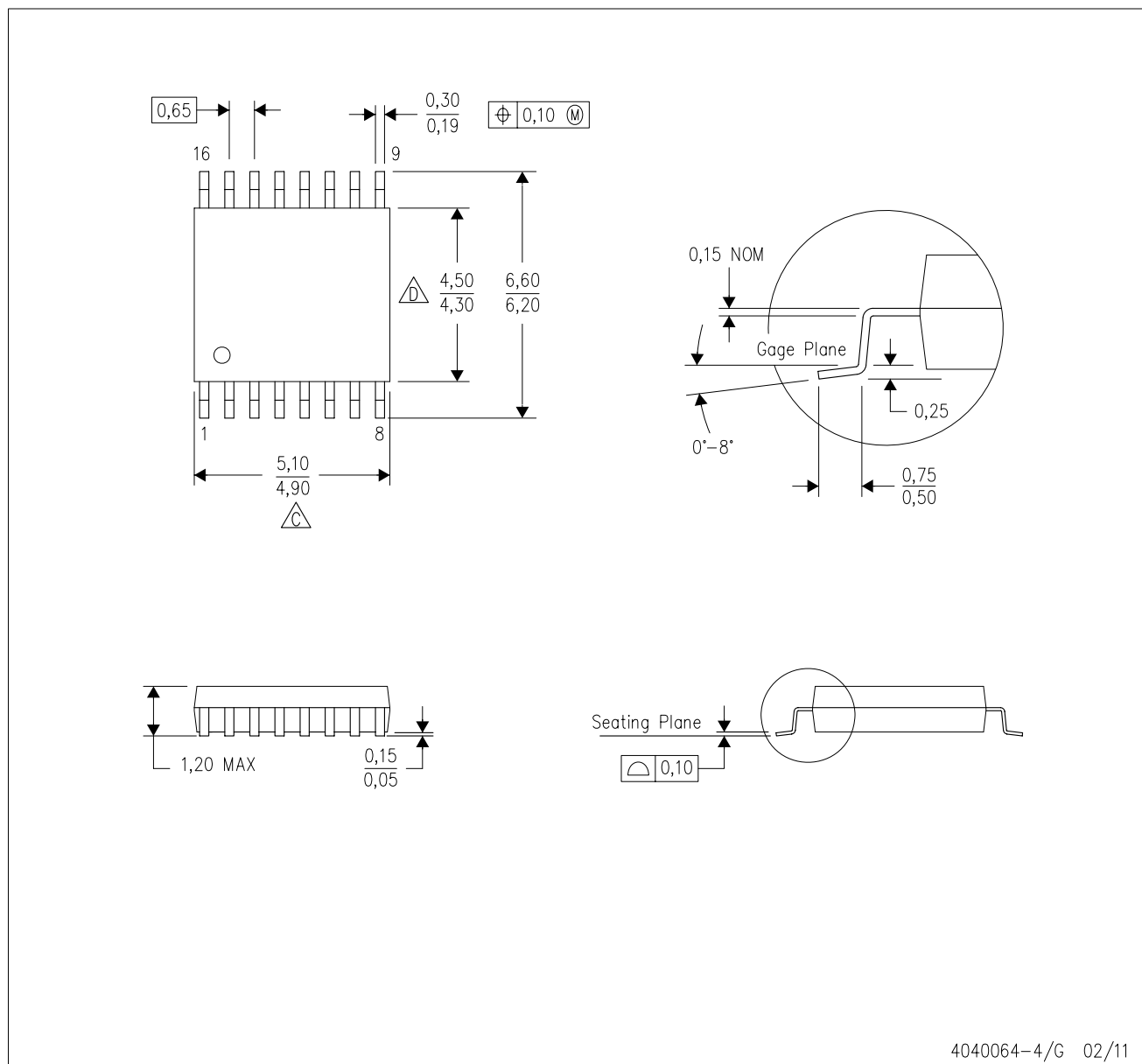
PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G16)

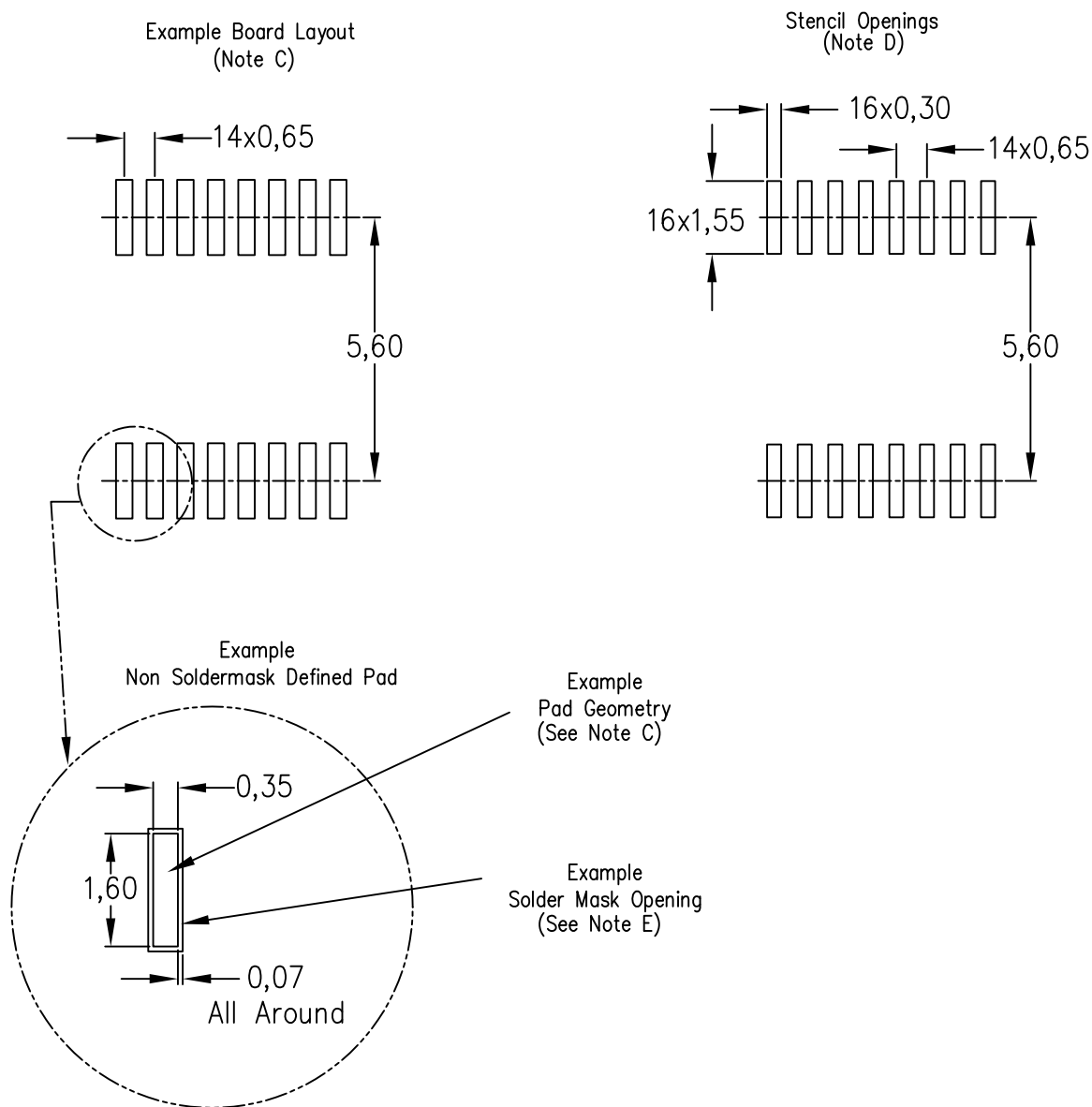
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - ⚠ C Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - ⚠ D Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4211284-3/F 12/12

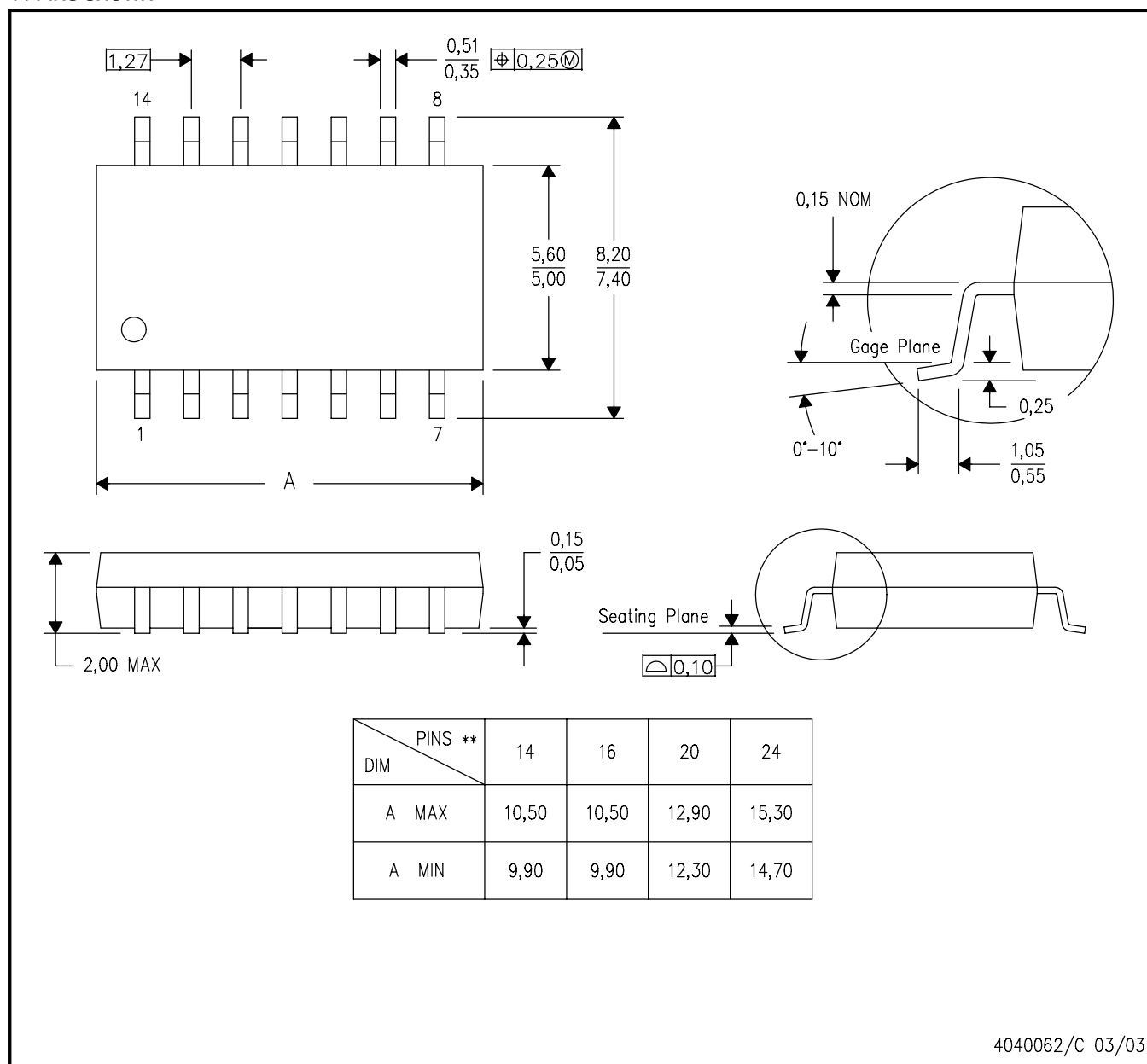
- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

MECHANICAL DATA

NS (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN

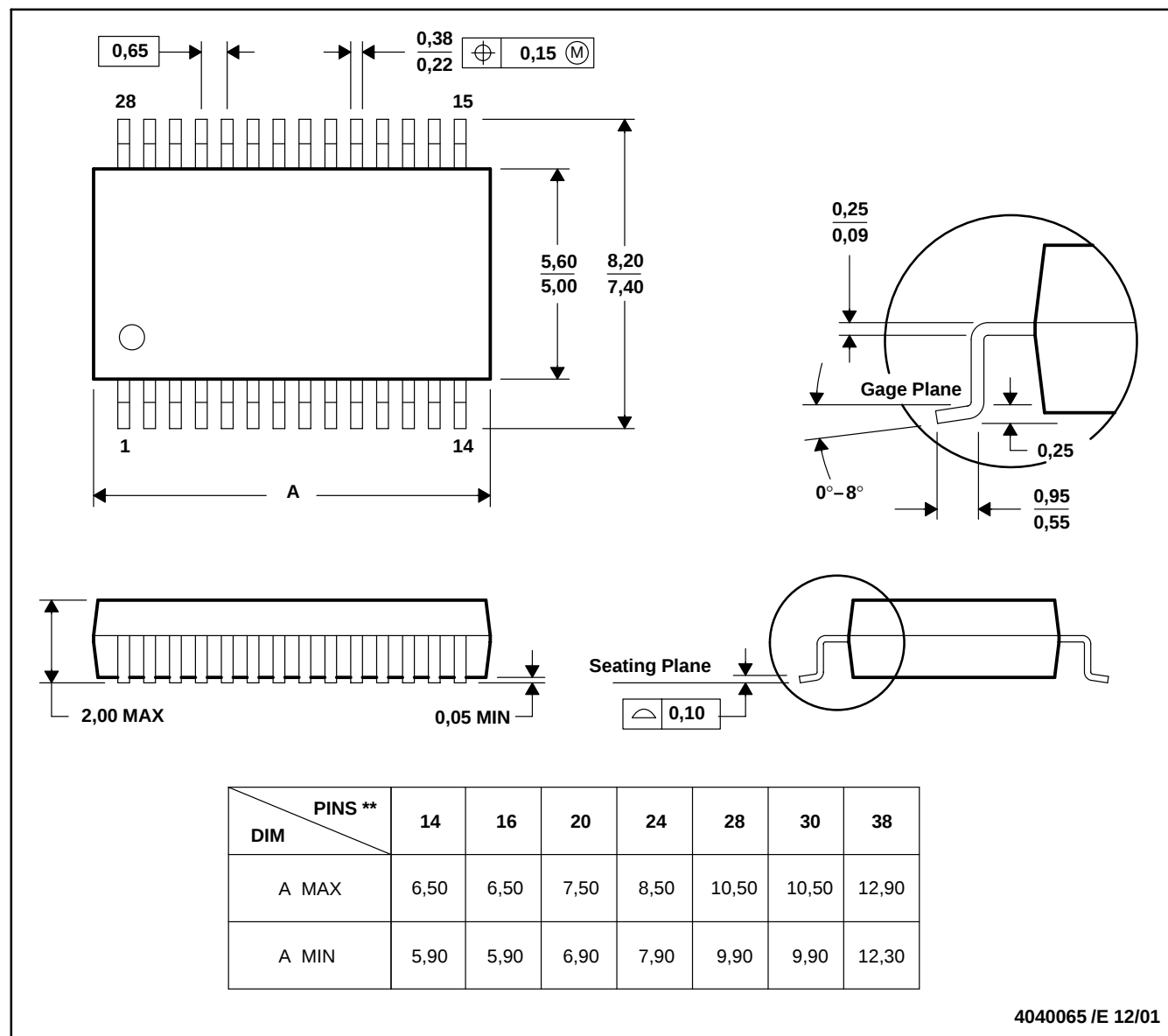


- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-150

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